## EE 321 Analog Electronics, Fall 2012 Exam 1 October 1, 2012 Solution

This is a closed-book exam. Calculators allowed. The exam is designed for conceptual understanding not long derivations. You MUST box your answer. Correct answer boxed and derivation gives you 10 points. Either is 5 points. Neither is 0 points.

You have a source,  $v_S$  with output resistance  $R_S = 1 \,\mathrm{k}\Omega$ , amplifier A with gain  $A_{voA} = 10$ ,  $R_{inA} = 1 \,\mathrm{k}\Omega$ , and  $R_{outA} = 10 \,\mathrm{k}\Omega$ , amplifier B with gain  $A_{voB} = 10$ ,  $R_{inB} = 10 \,\mathrm{k}\Omega$ , and  $R_{outB} = 1 \,\mathrm{k}\Omega$ , and a load  $R_L = 1 \,\mathrm{k}\Omega$ . Which arrangement, source-A-B-load, or source-B-A-load will result in the largest overall  $G_v$ , and what is that value?

1. Compute  $G_v$  for the source-A-B-load sequence.

$$G_v = \frac{R_{\text{inA}}}{R_{\text{inA}} + R_S} \times A_{voA} \times \frac{R_{\text{inB}}}{R_{\text{outA}} + R_{\text{inB}}} \times A_{voB} \times \frac{R_L}{R_L + R_{\text{outB}}}$$
$$= \frac{1}{1+1} \times 10 \times \frac{10}{10+10} \times 10 \times \frac{1}{1+1}$$
$$= 12.5$$

2. Compute  $G_v$  for the source-B-A-load sequence and indicate which of the two sequences produces the greater  $G_v$ .

$$G_v = \frac{10}{10+1} \times 10 \times \frac{1}{1+1} \times 10 \times \frac{1}{1+10}$$
  
=4.13

Thus, SABL configuration creates the larger gain.

We model an op-amp open-loop gain in the usual way as a LP circuit with  $A_0 = 10^6$  and  $f_0 = 10$  Hz.

3. What is the bandwidth of an amplifier, built with this op-amp, which has a gain of  $10^3$ ?

GBWP =  $10 \times 10^6 = 10^7$ . BW =  $\frac{\text{GBWP}}{G} = \frac{10^7}{10^3} = 10^4 \text{ Hz}.$ 

4. If you cascade two amplifiers to get a total gain of  $10^3$ , what is the bandwidth?

BW = 
$$\frac{\text{GBWP}}{\sqrt{G}} = \frac{10^7}{\sqrt{10^3}} = 3.2 \times 10^5 \text{ Hz}.$$

An op-amp has  $V_{OS} = 1 \text{ mV}$  and  $I_B = 1 \mu \text{A}$ . You use it to build a inverting amplifier with input resistance  $1 \text{ k}\Omega$ .

5. If the gain is -100 how big (absolute value) can the output get for zero input?

The effect of  $V_{OS}$  is

$$V_o = (|G| + 1) V_{OS} = 101 \times 10^{-3} = 101 \,\mathrm{mV}$$

The effect of  $I_B$  is

$$V_o = -I_B R_2 = I_B G R_1 = -100 \times 10^{-6} \times 10^3 = -100 \,\mathrm{mV}$$

Total effect is (absoluate)  $V_O = 201 \text{ mV}$ .

6. What value of the gain will produce a maximum (again absolute) output of 1 V?

Write (in absolute terms)

$$V_o = I_B |G| R_1 + (|G| + 1) V_{OS}$$

$$G| = \frac{V_O - V_{OS}}{I_B R_1 + V_{OS}} = \frac{1 - 10^{-3}}{10^{-6} \times 10^3 + 10^{-3}} = 500$$

so G = -500 is the largest we can allow.

Consider this diode circuit with  $R = 10 \Omega$ . Compute the value of  $V_o$  for three different values of  $V_i$ , -2 V, 1 V, and 3 V in the two cases below.



7. When modeling the diode as a fixed voltage drop,  $V_D = 0.7 \text{ V}$ .

In this case output equals  $V_D$  when  $V_i \ge V_D$ . So the answers are -2 V, 0.7 V, and 0.7 V.

8. When modeling the diode as a piecewise linear model with  $V_{D0} = 0.65 \text{ V}$ , and  $r_D = 5 \Omega$ .

in this case the output equals

$$V_O = \begin{cases} 0 & V_i < V_{D0} \\ V_{D0} + \frac{V_i - V_{D0}}{3} & V_i > V_{D0} \end{cases}$$

So we get for the three cases -2 V, 0.77 V, and 1.43 V.